

## N-Channel Power MOSFET

30V, 55A, 8mΩ

### FEATURES

- Fast switching
- 100% EAS Guaranteed
- Green Device Available
- G-S ESD Protection Diode Embedded

### APPLICATION

- Vcore / MB
- POL Application
- SMPS 2<sup>nd</sup> SR

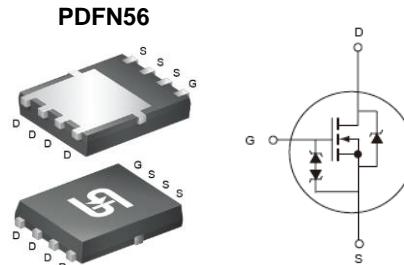
### KEY PERFORMANCE PARAMETERS

PARAMETER	VALUE	UNIT
$V_{DS}$	30	V
$R_{DS(on)}$ (max)	8	mΩ
	12.5	
$Q_g$	7.5	nC



✓  
RoHS  
COMPLIANT

HALOGEN  
FREE



**Notes:** Moisture sensitivity level: level 3. Per J-STD-020

### ABSOLUTE MAXIMUM RATINGS ( $T_A = 25^\circ\text{C}$ unless otherwise noted)

PARAMETER	SYMBOL	LIMIT	UNIT
Drain-Source Voltage	$V_{DS}$	30	V
Gate-Source Voltage	$V_{GS}$	$\pm 20$	V
Continuous Drain Current <sup>(Note 1)</sup>	$I_D$	55	A
		35	
Pulsed Drain Current <sup>(Note 2)</sup>	$I_{DM}$	220	A
Total Power Dissipation @ $T_C = 25^\circ\text{C}$	$P_{DTOT}$	54	W
Single Pulsed Avalanche Energy <sup>(Note 3)</sup>	$E_{AS}$	45	mJ
Single Pulsed Avalanche Current <sup>(Note 3)</sup>	$I_{AS}$	30	A
Operating Junction and Storage Temperature Range	$T_J, T_{STG}$	- 55 to +150	°C

### THERMAL PERFORMANCE

PARAMETER	SYMBOL	LIMIT	UNIT
Junction to Case Thermal Resistance	$R_{\text{eJC}}$	2.3	°C/W
Junction to Ambient Thermal Resistance	$R_{\text{eJA}}$	62	°C/W

**Notes:**  $R_{\text{eJA}}$  is the sum of the junction-to-case and case-to-ambient thermal resistances. The case thermal reference is defined at the solder mounting surface of the drain pins.  $R_{\text{eJA}}$  is guaranteed by design while  $R_{\text{eCA}}$  is determined by the user's board design.  $R_{\text{eJA}}$  shown below for single device operation on FR-4 PCB in still air.

<b>ELECTRICAL SPECIFICATIONS</b> ( $T_A = 25^\circ\text{C}$ unless otherwise noted)						
<b>PARAMETER</b>	<b>CONDITIONS</b>	<b>SYMBOL</b>	<b>MIN</b>	<b>TYP</b>	<b>MAX</b>	<b>UNIT</b>
<b>Static</b> <sup>(Note 4)</sup>						
Drain-Source Breakdown Voltage	$V_{GS} = 0\text{V}$ , $I_D = 250\mu\text{A}$	$BV_{DSS}$	30	--	--	V
Gate Threshold Voltage	$V_{DS} = V_{GS}$ , $I_D = 250\mu\text{A}$	$V_{GS(\text{TH})}$	1	1.6	2.5	V
Gate Body Leakage	$V_{GS} = \pm 20\text{V}$ , $V_{DS} = 0\text{V}$	$I_{GSS}$	--	--	$\pm 10$	$\mu\text{A}$
Zero Gate Voltage Drain Current	$V_{DS} = 30\text{V}$ , $V_{GS} = 0\text{V}$	$I_{DSS}$	--	--	1	$\mu\text{A}$
Drain-Source On-State Resistance	$V_{GS} = 10\text{V}$ , $I_D = 16\text{A}$	$R_{DS(\text{on})}$	--	6.5	8	$\text{m}\Omega$
	$V_{GS} = 4.5\text{V}$ , $I_D = 8\text{A}$			9.5	12.5	$\text{m}\Omega$
<b>Dynamic</b> <sup>(Note 5)</sup>						
Total Gate Charge	$V_{DS} = 15\text{V}$ , $I_D = 20\text{A}$ , $V_{GS} = 4.5\text{V}$	$Q_g$	--	7.5	--	nC
Gate-Source Charge		$Q_{gs}$	--	1.3	--	
Gate-Drain Charge		$Q_{gd}$	--	4.5	--	
Input Capacitance	$V_{DS} = 25\text{V}$ , $V_{GS} = 0\text{V}$ , $f = 1.0\text{MHz}$	$C_{iss}$	--	750	--	pF
Output Capacitance		$C_{oss}$	--	150	--	
Reverse Transfer Capacitance		$C_{rss}$		110		
Gate Resistance	$f = 1\text{MHz}$ , open drain	$R_g$	--	2.7	--	$\Omega$
<b>Switching</b> <sup>(Note 6)</sup>						
Turn-On Delay Time	$V_{DD} = 15\text{V}$ , $R_{\text{GEN}} = 3.3\Omega$ , $I_D = 15\text{A}$ , $V_{GS} = 10\text{V}$ ,	$t_{d(\text{on})}$	--	4.8	--	ns
Turn-On Rise Time		$t_r$	--	12.5	--	
Turn-Off Delay Time		$t_{d(\text{off})}$	--	27.6	--	
Turn-Off Fall Time		$t_f$	--	8.2	--	
<b>Source-Drain Diode</b> <sup>(Note 4)</sup>						
Forward On Voltage	$I_S = 1\text{A}$ , $V_{GS} = 0\text{V}$	$V_{SD}$	--	--	1	V

**Notes:**

1. Current limited by package
2. Pulse width limited by the maximum junction temperature
3.  $L = 0.1\text{mH}$ ,  $I_{AS} = 30\text{A}$ ,  $V_{DD} = 25\text{V}$ ,  $R_G = 25\Omega$ , Starting  $T_J = 25^\circ\text{C}$
4. Pulse test:  $PW \leq 300\mu\text{s}$ , duty cycle  $\leq 2\%$
5. For DESIGN AID ONLY, not subject to production testing.
6. Switching time is essentially independent of operating temperature.

**ORDERING INFORMATION**

PART NO.	PACKAGE	PACKING
TSM080N03EPQ56 RLG	PDFN56	2,500pcs / 13" Reel

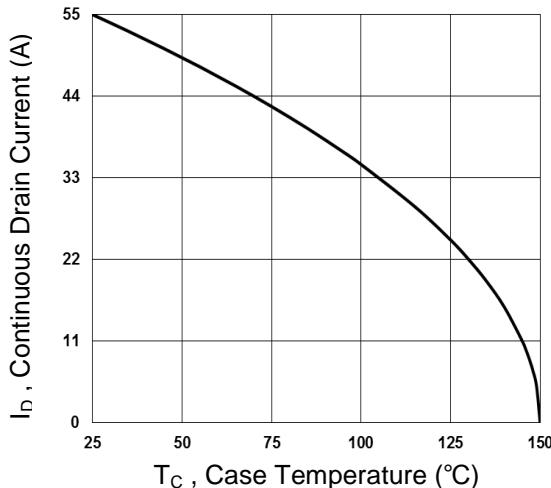
**Note:**

1. Compliant to RoHS Directive 2011/65/EU and in accordance to WEEE 2002/96/EC
2. Halogen-free according to IEC 61249-2-21 definition

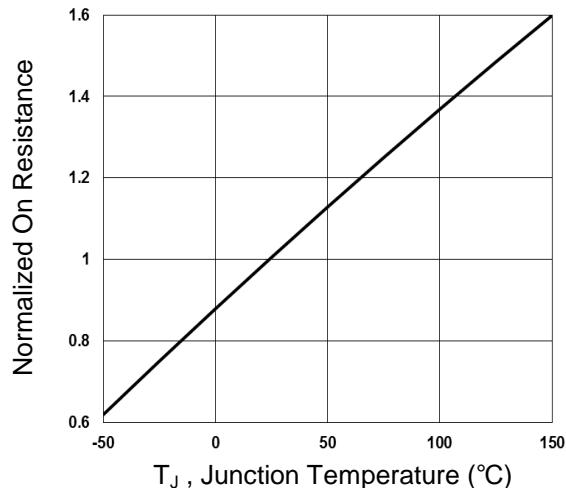
## CHARACTERISTICS CURVES

( $T_C = 25^\circ\text{C}$  unless otherwise noted)

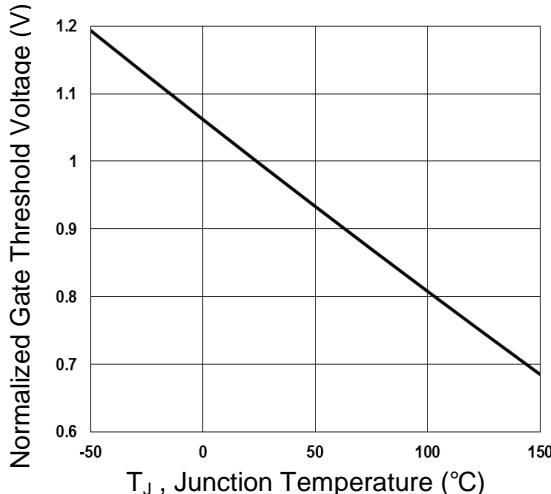
Continuous Drain Current vs.  $T_C$



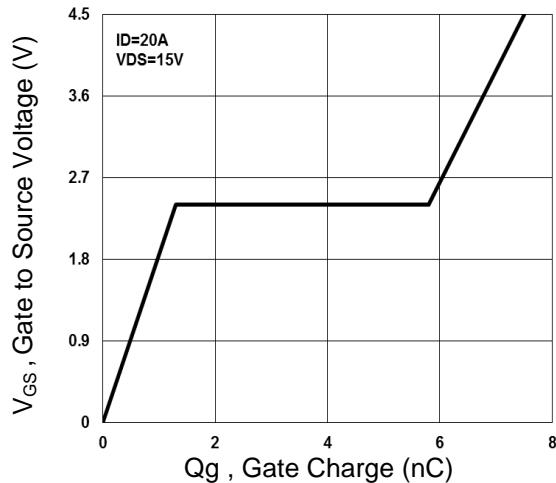
Normalized RDSON vs.  $T_J$



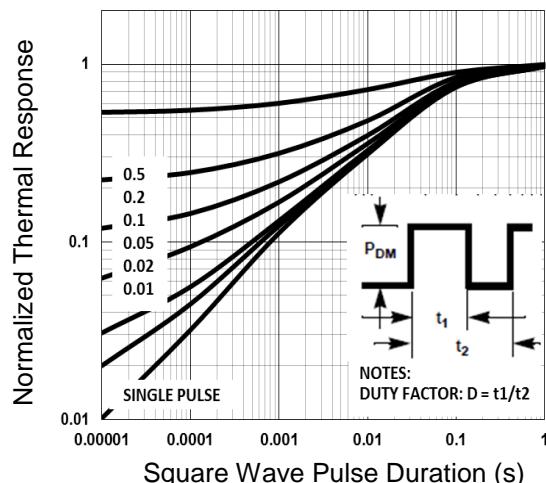
Normalized  $V_{th}$  vs.  $T_J$



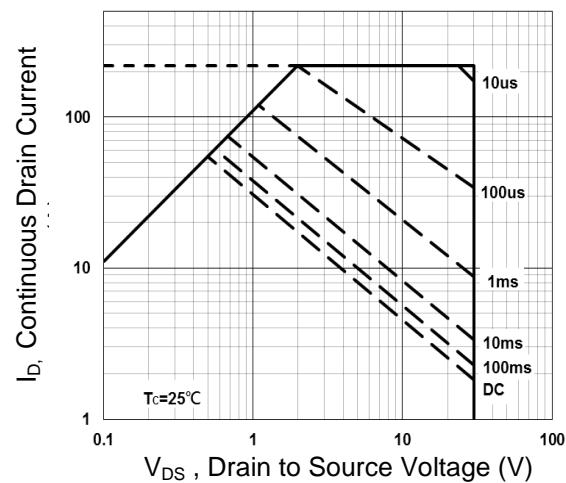
Gate Charge Waveform

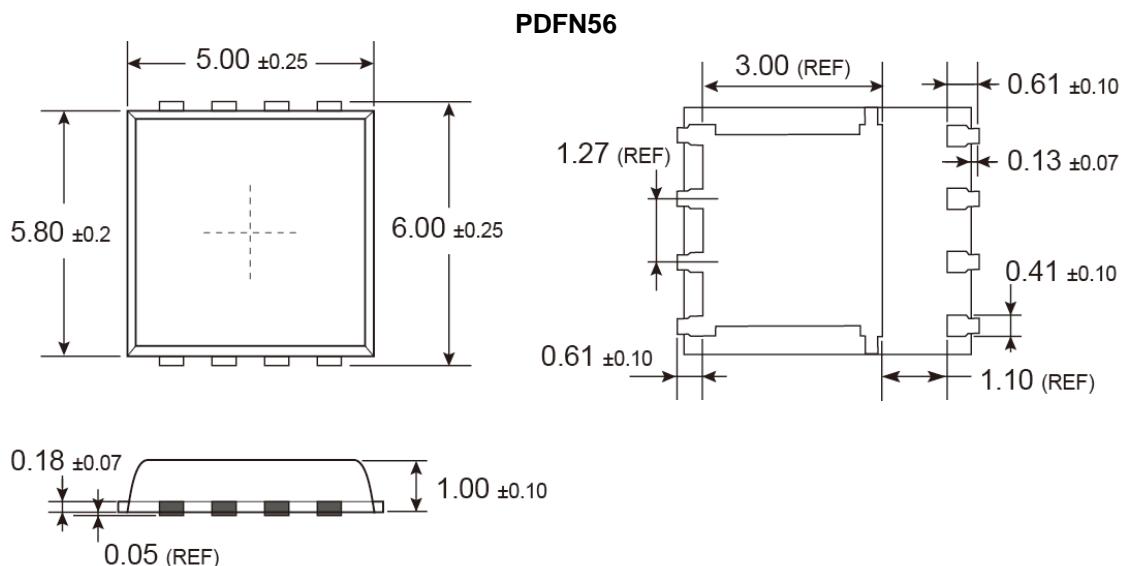
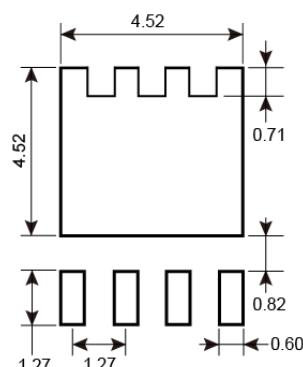


Normalized Transient Impedance



Maximum Safe Operation Area



**PACKAGE OUTLINE DIMENSIONS** (Unit: Millimeters)

**SUGGESTED PAD LAYOUT** (Unit: Millimeters)

**MARKING DIAGRAM**

**Y** = Year Code

**M** = Month Code for Halogen Free Product

**O** =Jan   **P** =Feb   **Q** =Mar   **R** =Apr

**S** =May   **T** =Jun   **U** =Jul   **V** =Aug

**W** =Sep   **X** =Oct   **Y** =Nov   **Z** =Dec

**L** = Lot Code (1~9, A~Z)

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